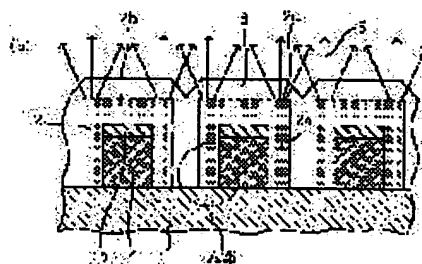
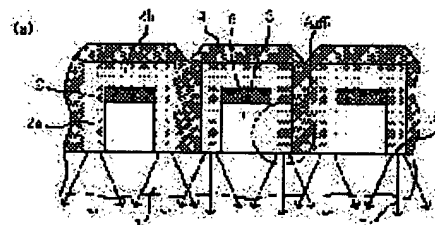


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(b) Or a negative electrode 4 and a pattern of an electron injection blocking layer 10 are formed on a substrate 1 in a stripe form in a rectangular shape of cross section. The surroundings of the negative electrode 4 and the pattern of the electron injection blocking



layer 10 are enclosed by a luminous material layer 2, and its outside is surrounded by a positive electrode 6. The light emitted at the hole/electron recombination layer 9 of the luminous material layer 2 held between the positive electrode 6 and the negative electrode 4 is taken out as a valid light 5 from the side end face 1a of the luminous material layer or from the top face 1e of the luminous material layer.

LEGAL STATUS

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